NSN 5961-00-110-0775

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-110-0775 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.030 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-94 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 110.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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